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# SE30ND, SE30NG, SE30NJ

## Vishay General Semiconductor

## **Surface-Mount Standard Rectifier**



Anode O Cathode

## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub> 3 A							
V <sub>RRM</sub>	200 V, 400 V, 600 V						
I <sub>FSM</sub>	40 A						
V <sub>F</sub> at I <sub>F</sub> = 3 A (T <sub>J</sub> = 125 °C)	0.86 V						
T <sub>J</sub> max.	175 °C						
Package	DFN3820A						
Circuit configuration	Single						

### **FEATURES**

- Low-profile package- typical height of 0.88 mm
- Leadless DFN package with side-wettable flanks suitable for customer AOI (Automatic Optical Inspection)
- · Ideal for automated replacement
- Oxide planar chip junction
- Low forward voltage drop
- Typical IR less than 0.1 μA
- ESD capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available
  Automotive ordering code: base P/NHM3
- Compatible to SMP (DO-220AA) package case outline
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

General purpose, power line polarity protection and rail-to-rail protection in consumer, industrial, and automotive applications.

### **MECHANICAL DATA**

#### Case: DFN3820A

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test **Polarity:** color band denotes cathode end

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	SE30ND	SE30NG	SE30NJ	UNIT			
Device marking code		3D	3G	3J				
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	200	400	600	V			
Maximum average forward rectified current (fig.1)	I <sub>F(AV)</sub> <sup>(1)</sup>		А					
Maximum average forward rectilied current (lig. r)	I <sub>F(AV)</sub> <sup>(2)</sup>							
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>		А					
Operating junction temperature range	T <sub>J</sub> <sup>(3)</sup>		°C					
Storage temperature range	T <sub>STG</sub>							

#### Notes

<sup>(1)</sup> Mounted on 20 x 20mm pad area, 2 oz. FR4 PCB

<sup>(2)</sup> Free air, mounted on recommended copper pad area

 $^{(3)}$  The heat generated must be less than the thermal conductivity from junction-to-ambient: dP<sub>D</sub>/dT<sub>J</sub> < 1/R<sub>0JA</sub>

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1

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RoHS

COMPLIANT HALOGEN

FREE



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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_J = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT		
Instantaneous forward voltage	I <sub>F</sub> = 1.5 A	T <sub>.1</sub> = 25 °C	- V <sub>F</sub> <sup>(1)</sup>	0.91	-	V		
	I <sub>F</sub> = 3 A	1j=25 C		0.97	1.1			
	I <sub>F</sub> = 1.5 A	T <sub>.1</sub> = 125 °C		0.79	-			
	I <sub>F</sub> = 3 A	1j=125 0		0.86	0.98			
Reverse current	Rated V <sub>R</sub>	T <sub>J</sub> = 25 °C	I <sub>B</sub> <sup>(2)</sup>	-	10	μA		
	naleu v <sub>R</sub>	$T_J = 125 \text{ °C}$		13	100	μΑ		
Typical reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 01 \text{ A}, I_{rr} = 0.25 \text{ A}$		t <sub>rr</sub>	1500	-	ns		
Typical junction capacitance	4.0 V, 1 MHz		CJ	19	-	pF		

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise specified)								
PARAMETER SYMBOL TYP. MAX. UNIT								
Thermal resistance	R <sub>0JA</sub> (1)(2)	135	169	°C/W				
	R <sub>θJM</sub> <sup>(3)</sup>	5	6.3	C/W				

#### Notes

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ 

(2) Thermal resistance junction-to-ambient to follow JEDEC® 51-2A, device mounted on FR4 PCB, 2 oz., standard footprint

<sup>(3)</sup> Thermal resistance junction-to-mount to follow JEDEC 51-14 transient dual interface test method (TDIM)

### **IMMUNITY TO ELECTRICAL STATIC DISCHARGE TO THE FOLLOWING STANDARDS**

(T <sub>A</sub> = 25 $^{\circ}$ C unless otherwise noted)								
STANDARD	TEST TYPE	TEST CONDITIONS	SYMBOL	CLASS	VALUE			
AEC-Q101-001	Human body model (contact mode)	C = 100 pF, R = 1.5 k $\Omega$		H3B	> 8 kV			
AEC-Q101-002	Machine model (contact mode)	C = 200 pF, R = 0 $\Omega$		M4	> 400 V			
JESD22-A114	Human body model (contact mode)	C = 100 pF, R = 1.5 k $\Omega$	V	3B	> 8 kV			
JESD22-A115	Machine model (contact mode)C = 200 pF, R = 0 $\Omega$ V <sub>C</sub>		С	> 400 V				
IEC 61000-4-2 <sup>(2)</sup>	Human body model (contact mode)	C = 150 pF, R = 330 $\Omega$		4	> 8 kV			
	Human body model (air-discharge mode) <sup>(1)</sup>	C = 150 pF, R = 330 $\Omega$		4	> 15 kV			

#### Notes

<sup>(1)</sup> Immunity to IEC 61000-4-2 air discharge mode has a typical performance > 30 kV

(2) System ESD standard



# SE30ND, SE30NG, SE30NJ

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## **ORDERING INFORMATION TABLE**

		1	1				r
Device code	S	E	30	N	J	н	М3
	1	2	3	4	5	6	7
	1	- Vis	hay star	idard ree	covery p	oroduct	
	2	- Oxi	de plana	ar chip te	echnolog	ду	
	3	- Cur	rent rati	ng (30 =	= 3 A)		
	4	- Pao	kage ty	pe (N =	DFN pa	ckage)	
	5	- Vol	tage rati	ng (D =	200 V, (	G = 400	V, J = 6
	6	- Qua	ality gra	de (H = .	AEC-Q1	01 qual	ified, ot
	7				ient cate nd termi		

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
SE30NJ-M3/H	0.023	Н	3500	7" diameter plastic tape and reel				
SE30NJ-M3/I	0.023	I	14 000	13" diameter plastic tape and reel				
SE30NJHM3/H <sup>(1)</sup>	0.023	Н	3500	7" diameter plastic tape and reel				
SE30NJHM3/I <sup>(1)</sup>	0.023	I	14 000	13" diameter plastic tape and reel				

Note

<sup>(1)</sup> AEC-Q101 qualified



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## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

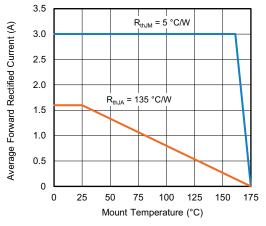


Fig. 1 - Maximum Forward Current Derating Curve

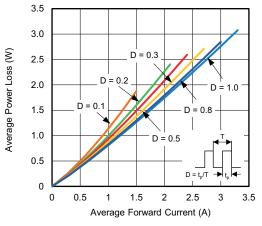


Fig. 2 - Forward Power Loss Characteristics

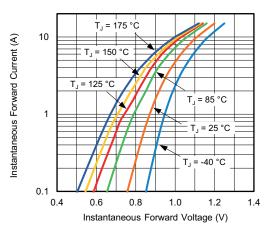


Fig. 3 - Typical Instantaneous Forward Characteristics

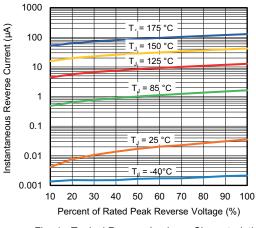


Fig. 4 - Typical Reverse Leakage Characteristics

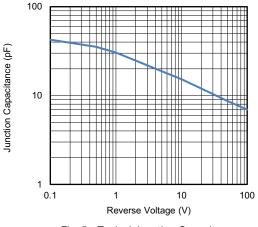


Fig. 5 - Typical Junction Capacitance

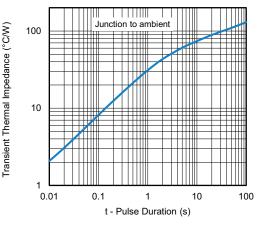


Fig. 6 - Typical Transient Thermal Impedance

Revision 06-Nov-2024

4

Document Number: 98368

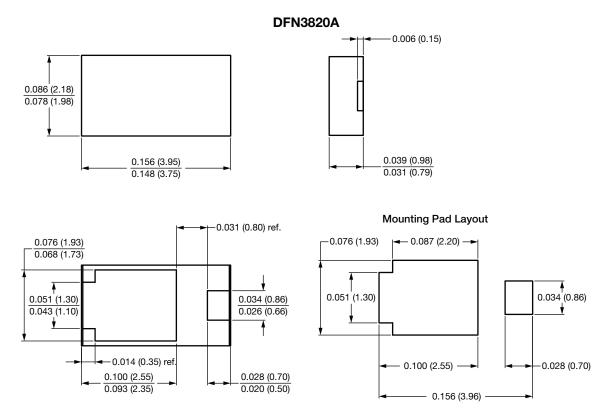
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## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)





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1